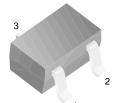


FJX2222A

General Purpose Transistor

- Collector-Emitter Voltage: V_{CEO} = 40V
 Collector Dissipation: P_C (max) = 325mW



SOT-323

1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	75	V
V _{CES}	Collector-Emitter Voltage	40	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current	600	mA
P _C	Collector Power Dissipation	350	mW
T _{STG}	Storage Temperature	150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =10μA, I _E =0	75		V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	40		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =10μA, I _C =0	6		V
I _{CBO}	Collector Cut-off Current	V _{CB} =60V, I _E =0		0.01	μΑ
h _{FE}	* DC Current Gain	V _{CE} =10V, I _C =0.1mA V _{CE} =10V, I _C =1mA V _{CE} =10V, I _C =10mA V _{CE} =10V, I _C =150mA V _{CE} =10V, I _C =500mA	35 50 75 100 40	300	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C =150mA, I _B =15mA I _C =500mA, I _B =50mA		0.3 1.0	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C =150mA, I _B =15mA I _C =500mA, I _B =50mA	0.6	1.2 2.0	V V
f _T	Current Gain Bandwidth Product	I _C =20mA, V _{CE} =20V, f=100MHz	300		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz	4	8	pF
NF	Noise Figure	I_C =100μA, V_{CE} =10V R_S =1K Ω , f=1kHz		4	dB
t _{ON}	Turn On Time	V _{CC} =30V, I _C =150mA V _{BE} =0.5V, I _{B1} =15mA		35	ns
t _{OFF}	Turn Off Time	V_{CC} =30V, I_{C} =150mA I_{B1} = I_{B2} =15mA		285	ns

^{*} Pulse Test: PW≤300µs, Duty Cycle≤2%

Marking



Typical Characteristics

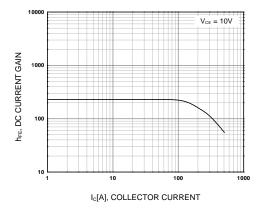


Figure 1. DC current Gain

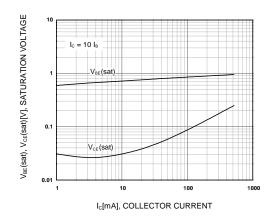


Figure 2. Collector-Base Saturation Voltage Base-Emitter Saturation Voltage

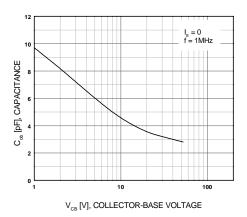


Figure 3. Output Capacitance

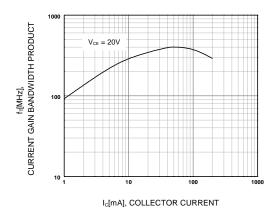
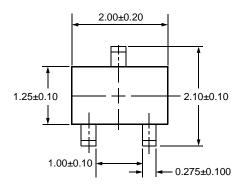
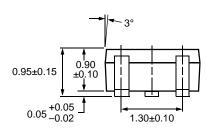


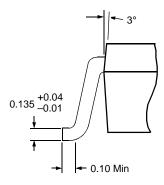
Figure 4. Current Gain Bandwidth Product

Package Demensions

SOT-323







Dimensions in Millimeters

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